

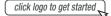
Vishay General Semiconductor

Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS

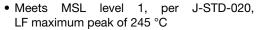




PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 30 A			
V_{RRM}	170 V			
I _{FSM}	210 A			
V _F at I _F = 30 A	0.72 V			
T _J max.	175 °C			
Package	D ² PAK (TO-263AB)			
Circuit configuration	Common cathode			

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation





 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: D²PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER			VB60170G	UNIT		
Maximum repetitive peak reverse voltage		V_{RRM}	170	V		
Maximum average forward rectified current	per device	I _{F(AV)}	60	Α		
(fig. 1)	per diode		30			
Peak forward surge current 8.3 ms single half sine-wave supe	I _{FSM}	210	Α			
Voltage rate of change (rated V _R)		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		T_J , T_{STG}	-40 to +175	°C		

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A		V _F ⁽¹⁾	0.65	-	V	
	I _F = 15 A	T _A = 25 °C		0.78	-		
	I _F = 30 A			0.87	1.02		
	I _F = 5 A	T _A = 125 °C		0.50	-		
	I _F = 15 A			0.62	-		
	I _F = 30 A			0.72	0.80		
Reverse current per diode	V _R = 136 V	T _A = 25 °C	I _R ⁽²⁾	1.5	-	μΑ	
		T _A = 125 °C		2.5	-	mA	
	V _R = 170 V	T _A = 25 °C		-	450	μΑ	
		T _A = 125 °C		5	50	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 20 ms



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THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VB60170G	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	1.0	°C/W	
	per device		0.7	C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB60170G-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB60170G-E3/8W	1.38	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

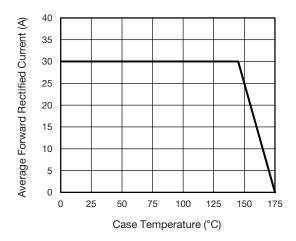


Fig. 1 - Maximum Forward Current Derating Curve

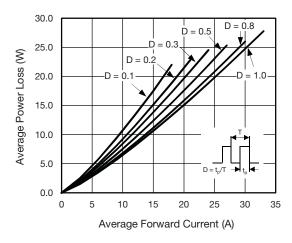


Fig. 2 - Forward Power Loss Characteristics Per Diode

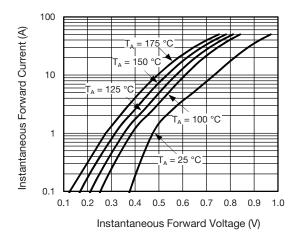


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

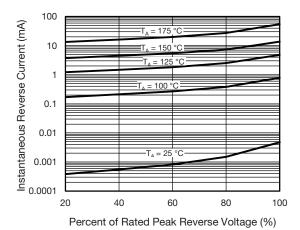


Fig. 4 - Typical Reverse Characteristics Per Diode



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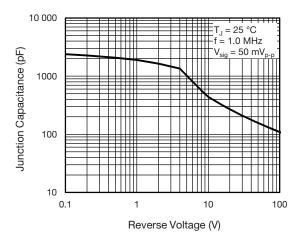


Fig. 5 - Typical Junction Capacitance Per Diode

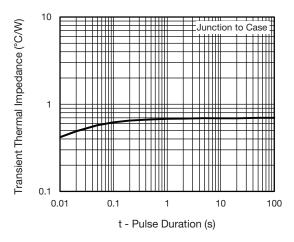
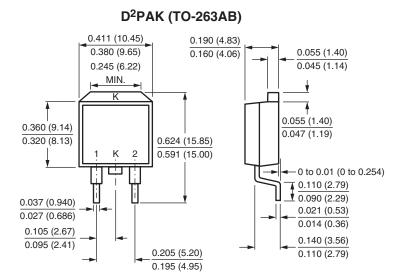
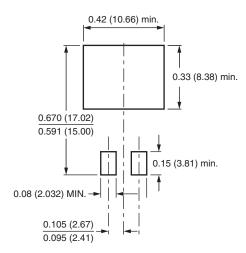


Fig. 6 - Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Mounting Pad Layout





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